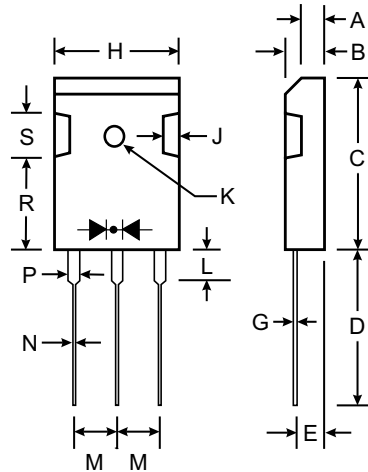


Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- Plastic Material: UL Flammability Classification Rating 94V-0

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Body
- Marking: Type Number
- Weight: 5.6 grams (approx.)
- Mounting Position: Any



TO-3P		
Dim	Min	Max
A	3.20	3.50
B	4.59	5.16
C	20.80	21.30
D	19.70	20.20
E	2.10	2.40
G	0.51	0.76
H	15.90	16.40
J	1.70	2.70
K	3.10 \varnothing	3.30 \varnothing
L	3.50	4.51
M	5.20	5.70
N	1.12	1.22
P	1.93	2.18
Q	2.97	3.22
R	11.70	12.80
S	4.30 Typical	
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	SBL 4030PT	SBL 4035PT	SBL 4040PT	SBL 4045PT	SBL 4050PT	SBL 4060PT	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	30	35	40	45	50	60	V
Working Peak Reverse Voltage	V _{RWM}							
DC Blocking Voltage	V _R							
RMS Reverse Voltage	V _{R(RMS)}	21	24.5	28	31.5	35	42	V
Average Rectified Output Current @ T _C = 100°C (Note 1)	I _O	40						A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	375						A
Forward Voltage Drop @ I _F = 20A, T _C = 25°C	V _{FM}	0.58				0.70		V
Peak Reverse Current @ T _C = 25°C at Rated DC Blocking Voltage @ T _C = 100°C	I _{RM}					1.0 100		mA
Typical Junction Capacitance (Note 2)	C _j					800		pF
Typical Thermal Resistance Junction to Case (Note 1)	R _{θJc}					1.4		°C/W
Operating Temperature Range	T _j					-55 to +125		°C
Storage Temperature Range	T _{STG}					-55 to +150		°C

- Notes: 1. Thermal resistance junction to case mounted on heatsink.
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

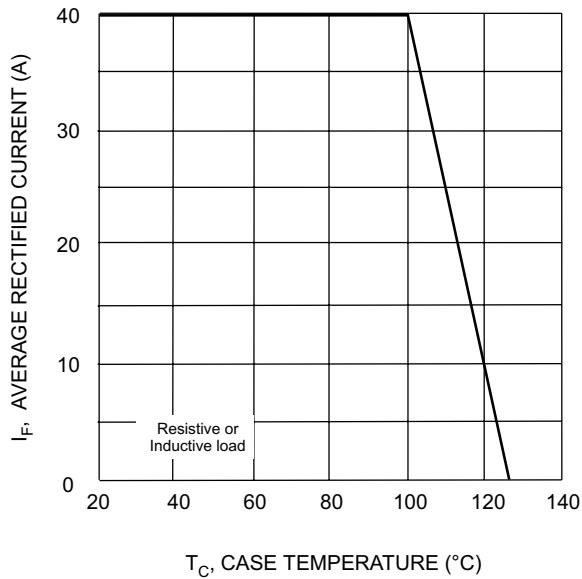


Fig. 1 Forward Current Derating Curve

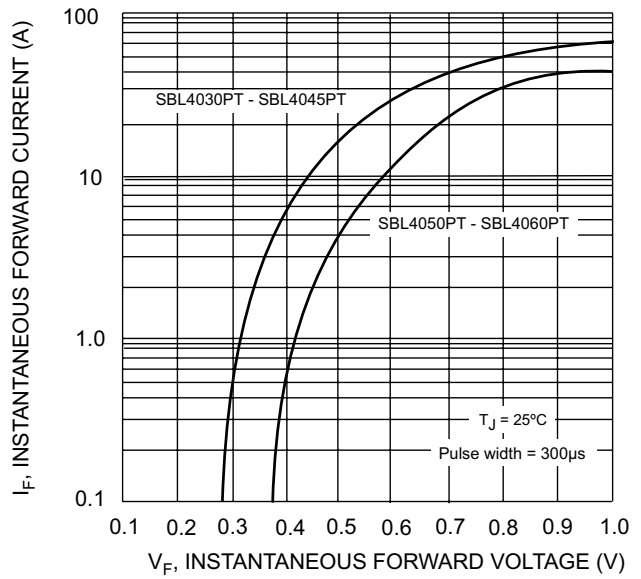


Fig. 2 Typical Forward Characteristics

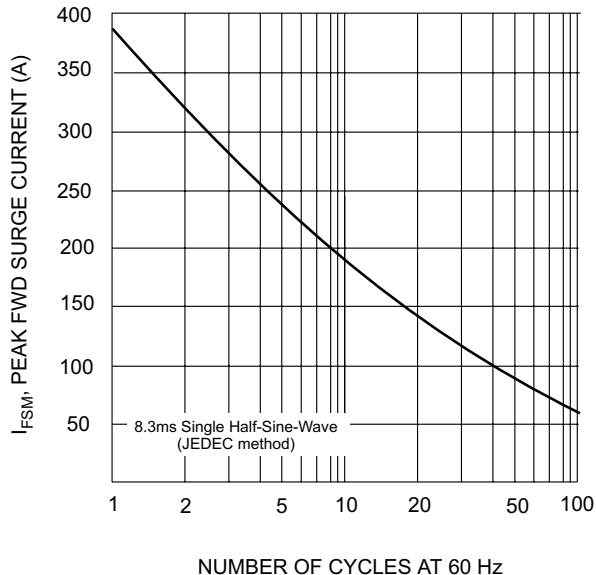


Fig. 3 Max Non-Repetitive Surge Current

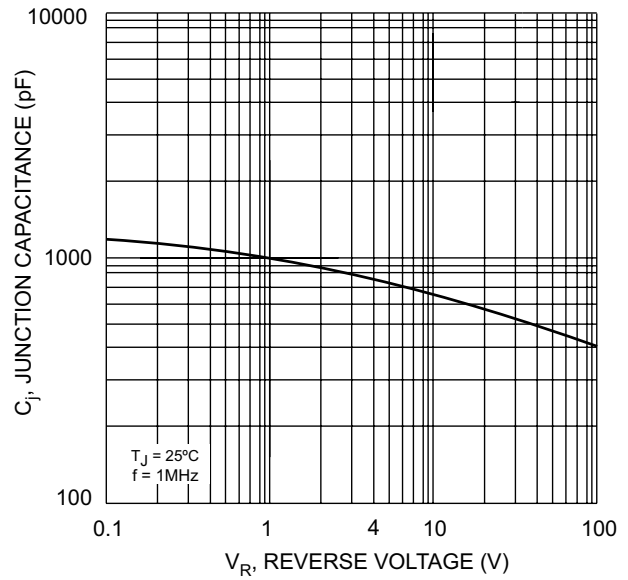


Fig. 4 Typical Junction Capacitance per Element

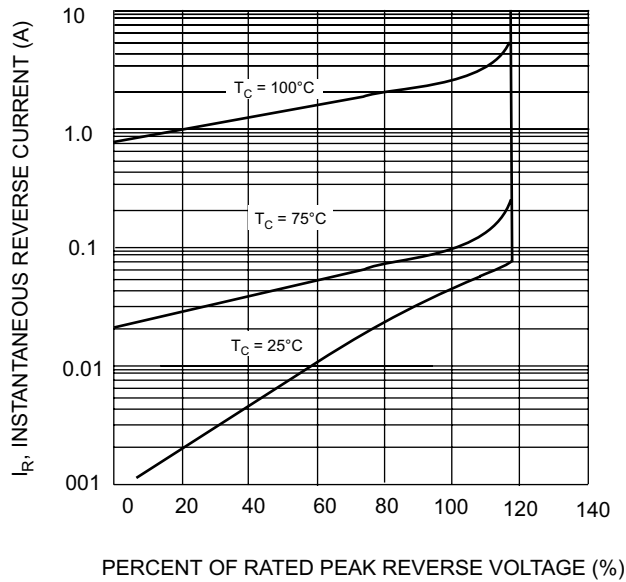


Fig. 5 Typical Reverse Characteristics